

Supporting information

Synthesis and characterization of materials

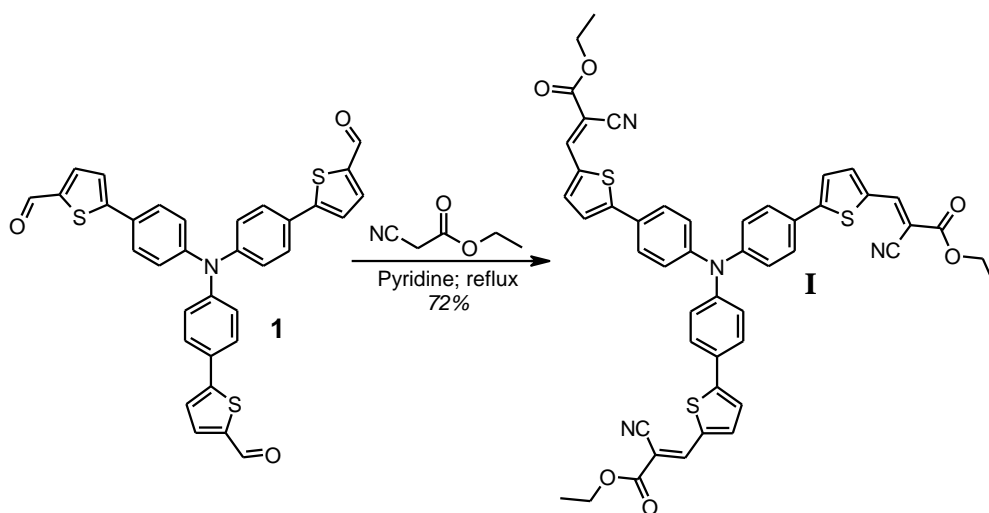
Materials

n-Butyllithium solution, 1.6 M in hexanes (*n*-BuLi), 2-ethylhexyl and 2-ethyl cyanoacetate, tetrakis(triphenylphosphine) palladium (0) (Pd(PPh₃)₄), heptanoyl chloride, tin tetrachloride were obtained from Sigma-Aldrich Co. and used without further purification. THF, pyridine, toluene and *N,N*-dimethylformamide (DMF) were dried and purified according to the known techniques.

5,5',5''-[Nitrilotris(4,1-phenylene)]trithiophene-2-carbaldehyde (**1**) was obtained as described in previous work [40]. 4-Bromo-7-(2-thienyl)-2,1,3-benzothiadiazole (**2**) [41] and 4,4',4''-tris(4,4,5,5-tetramethyl-1,3,2-dioxaborolan-2-yl)triphenylamine (**4**) [42] were obtained as reported elsewhere. All reactions, unless stated otherwise, were carried out under an inert atmosphere.

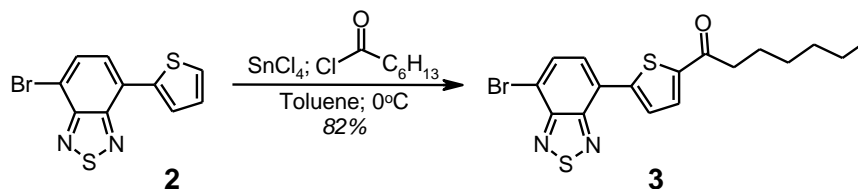
Synthesis

The elaborated synthetic route for the preparation of target materials **I** and **III** is shown on Scheme 1 of the manuscript, whereas the preparation of **II** and **IV** were described previously [32–34].

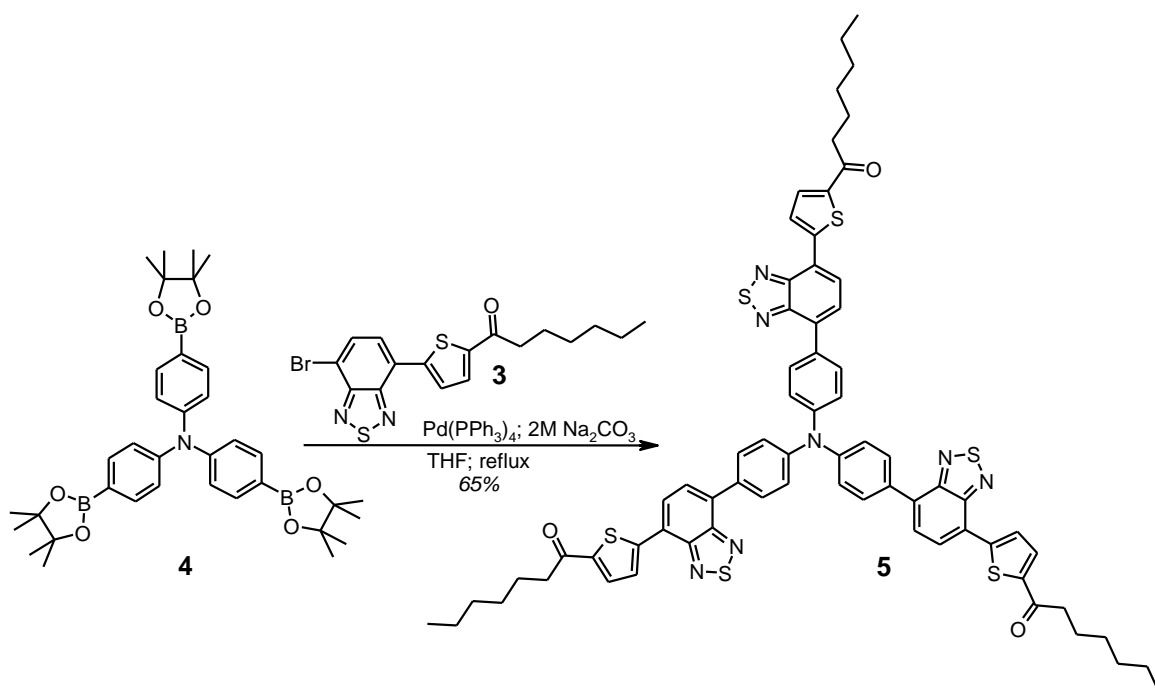


Triethyl(3,3',3''-((nitrilotris(benzene-4,1-diyl)))tris(thiophene-5,2-diyl))(2E,2'E,2''E)-tris(2-cyanoacrylate) (I). Compound **1** (1.21g, 2.1 mmol), 2-ethyl cyanoacetate (1.07 g, 9.5 mmol) and dry pyridine (37 mL) were placed in a reaction vessel and stirred for 10 hours at reflux temperature using the microwave heating. After reaction was completed, pyridine was evaporated under vacuum and the residue solid was dried. The crude product was purified by column chromatography on silica gel using dichloromethane: ethyl acetate (20/1, v/v) as an eluent followed

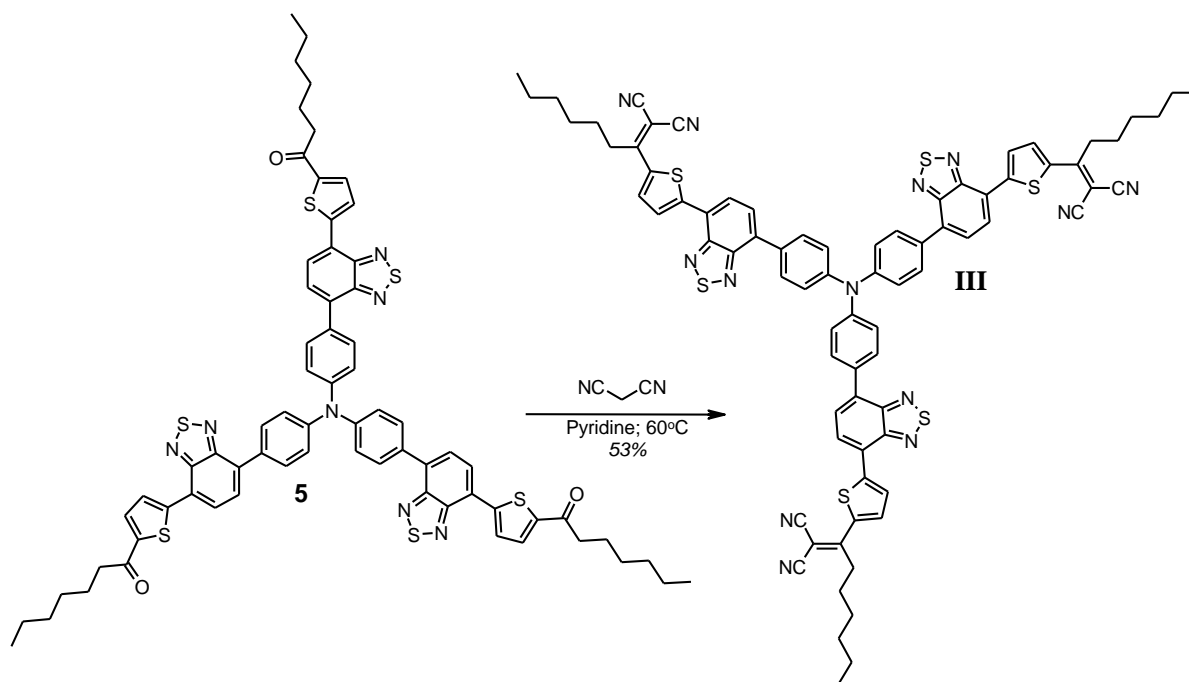
by recrystallization from dichloromethane/hexane mixture to give pure **I** (1.29 g, 72%) as a red solid. *M.p.* = 288 °C. ¹H NMR (250 MHz, CDCl₃): 1.35–1.41 (t, 9H, *J* = 7.02 Hz); 4.31 (q, 6H, *J* = 7.02 Hz); 7.19 (d, 6H, *J* = 8.85 Hz); 7.38 (d, 3H, *J* = 3.97 Hz); 7.65 (d, 6H, *J* = 8.55 Hz); 7.74 (d, 3H, *J* = 3.97 Hz); 8.29 (s, 3H). ¹³C NMR (75 MHz, CDCl₃): 14.08; 62.26; 98.37; 115.81; 123.92; 124.70; 127.77; 128.44; 134.81; 138.52; 145.95; 147.66; 153.69; 162.81. Calcd. (%) for C₄₈H₃₆N₄O₆S₃: C, 66.96; H, 4.21; N, 6.51; S, 11.17. Found: C, 67.06; H, 4.23; N, 6.49; S, 11.16.



1-(5-(7-Bromobenzo[c][1,2,5]thiadiazol-4-yl)thiophen-2-yl)heptan-1-one (3). SnCl₄ (14.79 g, 56.8 mmol) was added dropwise to the mixture of 4-bromo-7-(2-thienyl)-2,1,3-benzothiadiazole (14.34 g, 48.3 mmol) and heptanoyl chloride (7.89 g, 53.1 mmol) in 300 mL of dry toluene at 0 °C. The reaction mixture was stirred for 1 h at 0 °C, then the cooling bath was removed, and the stirring was continued for overnight with raising the temperature to RT. After reaction was completed, the reaction mixture was washed with 1M HCl, 300 mL H₂O, 5% Na₂CO₃. The combined organic phases were dried over sodium sulfate, filtered, evaporated and dried under vacuum. The crude product was purified by column chromatography on silica gel using toluene as an eluent followed by recrystallization from toluene:hexane (1/5, v/v) to give pure compound **3** (16.19 g, 82%) as a brown solid. *M.p.* = 141 °C. ¹H NMR (250 MHz, CDCl₃): 0.88 (t, 3H, *J* = 7.02 Hz); 1.22–1.53 (m, 6H); 1.76 (q, 2H, *J* = 7.32 Hz); 2.93 (t, 2H, *J* = 7.32 Hz); 7.76 (d, 1H, *J* = 3.97 Hz); 7.81 (d, 1H, *J* = 7.63 Hz); 7.90 (d, 1H, *J* = 7.63 Hz); 8.09 (d, 1H, *J* = 3.97 Hz). ¹³C NMR (75 MHz, CDCl₃): 13.79; 22.36; 24.77; 28.94; 31.52; 39.41; 114.44; 126.25; 126.86; 128.44; 131.85; 132.04; 144.85; 145.48; 151.71; 153.91; 193.09. Calcd. (%) for C₁₇H₁₇BrN₂OS₂: C, 49.88; H, 4.19; N, 6.84; S, 15.67. Found: C, 49.97; H, 4.21; N, 6.88; S, 15.67.



1,1',1''-(((nitrilotris(benzene-4,1-diyl))tris(benzo[*c*][1,2,5]thiadiazole-7,4-diyl))tris(thiophene-5,2-diyl))tris(heptan-1-one) (5). Compound **3** (3.38 g, 9.0 mmol), compound **4** (1.70 g, 3.0 mmol), Pd(PPh₃)₄ (0.24 g, 0.5 mmol), 2M solution of Na₂CO₃ (9 mL, 25 mmol) and THF (250 mL) were placed in a reaction vessel and stirred under inert atmosphere for 8 hours at reflux temperature. After reaction was completed, the reaction mixture was concentrated under reduced pressure. The crude product was purified by recrystallization from toluene to give pure compound **5** (2.19 g, 65%) as a red solid. *M.p.* = 127 °C. ¹H NMR (250 MHz, CDCl₃): 0.90 (t, 9H, *J* = 7.02 Hz); 1.29–1.46 (m, 18H); 1.79 (q, 6H, *J* = 7.02 Hz); 2.98 (t, 6H, *J* = 7.32 Hz); 7.44 (d, 6H, *J* = 8.55 Hz); 7.74–7.80 (m, 6H); 7.99 (d, 6H, *J* = 8.55 Hz); 8.05 (d, 3H, *J* = 7.32 Hz); 8.15 (d, 3H, *J* = 3.96 Hz). ¹³C NMR (75 MHz, CDCl₃): 13.91; 22.45; 24.86; 29.02; 31.59; 39.38; 124.42; 125.07; 127.06; 127.95; 130.34; 131.87; 132.06; 133.67; 144.20; 146.66; 147.51; 152.79; 153.85; 193.31. Calcd. (%) for C₆₉H₆₃N₇O₃S₆: C, 67.34; H, 5.16; N, 7.97; S, 15.63. Found: C, 67.39; H, 5.16; N, 7.95; S, 15.64.



2,2',2''-((((nitrilotris(benzene-4,1-diyl))tris(benzo[*c*][1,2,5]thiadiazole-7,4-diyl))tris(thiophene-5,2-diyl))tris(heptan-1-yl-1-ylidene))trimalonitrile (III). Compound **5** (2.09 g, 1.7 mmol) and malononitrile (0.56 g, 8.5 mmol) were dissolved in pyridine (42 mL) in a round bottom flask under inert atmosphere. Then the mixture was stirred at 60°C for 8 h. After cooling to room temperature, the reaction mixture was concentrated under reduced pressure. The crude product was purified by column chromatography on silica gel using chloroform as an eluent, followed by recrystallization from toluene to give pure **III** (1.23 g, 53%) as a dark solid. *M.p.* = 257 °C. ¹H NMR (250 MHz, CDCl₃): 0.90 (t, 9H, *J* = 7.32 Hz); 1.29–1.40 (m, 12H); 1.43–1.54 (m, 6H); 1.76 (q, 6H, *J* = 7.63 Hz); 3.04 (t, 6H, *J* = 7.02 Hz); 7.46 (d, 6H, *J* = 8.54 Hz); 7.82 (d, 3H, *J* = 7.63 Hz); 8.03 (d, 6H, *J* = 8.54 Hz); 8.11 (d, 3H, *J* = 7.63 Hz); 8.14 (d, 3H, *J* = 4.28 Hz); 8.22 (d, 3H, *J* = 4.27 Hz). ¹³C NMR (75 MHz, CDCl₃): 13.98; 22.40; 29.15; 30.38; 31.23; 37.58; 77.45; 113.71; 114.53; 123.75; 124.42; 126.99; 127.40; 128.38; 130.38; 131.56; 134.27; 134.35 137.61; 147.47; 147.99; 152.43; 153.59; 167.04. Calcd. (%) for C₇₈H₆₃N₁₃S₆: C, 68.14; H, 4.62; N, 13.24; S, 13.99. Found: C, 68.21; H, 4.65; N, 13.20; S, 13.96. MALDI-TOF MS: found *m/z* 1372.76; calcd. for [M]⁺ 1373.37.

The Knövenagel condensation was carried out in the microwave “Discovery”, (CEM corporation, USA), using a standard method with the open vessel option, 30 watts.

Characterization

NMR spectra. ^1H NMR spectra were recorded using a “Bruker WP-250 SY” spectrometer, working at a frequency of 250 MHz and using CDCl_3 (7.25 ppm) signals as the internal standard. ^{13}C NMR spectra were recorded using a “Bruker Avance II 300” spectrometer, working at a frequency of 75 MHz. In the case of ^1H NMR spectroscopy, the compounds to be analyzed were taken in the form of 1% solutions in CDCl_3 . In the case of ^{13}C NMR spectroscopy, the compounds to be analyzed were taken in the form of 5% solutions in CDCl_3 . The spectra were then processed on the computer using the “ACD Labs” software.

Elemental analysis. Elemental analysis of C, N and H elements was carried out using CHN automatic analyzer “CE 1106” (Italy). The settling titration using BaCl_2 was applied to analyze the S element.

Mass-spectra. Mass-spectra (MALDI-TOF) were registered on an “Autoflex II Bruker” (resolution FWHM 18000), equipped with a nitrogen laser (work wavelength 337 nm) and time-of-flight mass-detector working in the reflections mode. The accelerating voltage was 20 kV. Samples were applied to a polished stainless-steel substrate. Spectrum was recorded in the positive ion mode. The resulting spectrum was the sum of 300 spectra obtained at different points of the sample. 2,5-Dihydroxybenzoic acid (DHB) (Acros, 99%) and α -cyano-4-hydroxycinnamic acid (HCCA) (Acros, 99%) were used as matrices.

Absorption spectra. The absorption spectra were recorded on a Shimadzu UV-2501PC (Japan) spectrophotometer in the standard 10 mm photometric quartz cuvette using THF solutions with the concentrations of 10^{-5} M. Films were cast from THF solutions on glass substrates. All measurements were carried out at room temperatures.

^1H and ^{13}C NMR Spectra

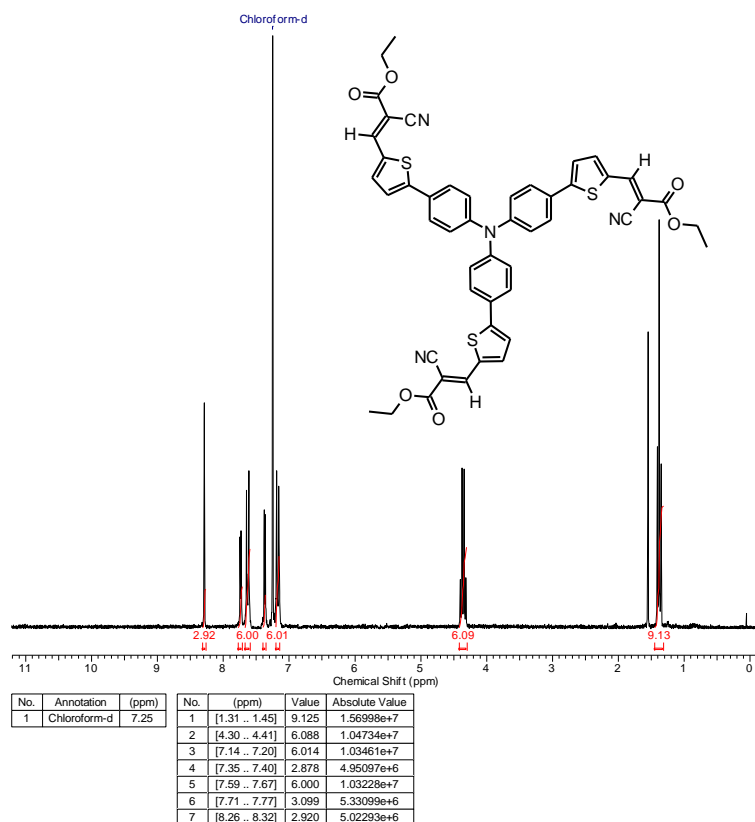


Figure S1. ^1H NMR spectrum of target material I.

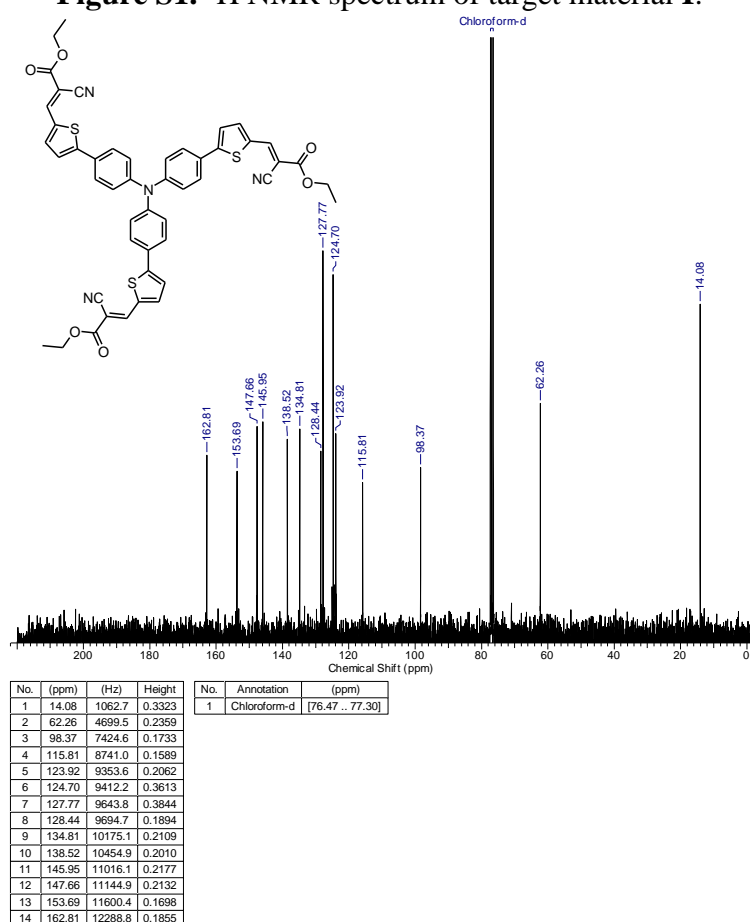


Figure S2. ^{13}C NMR spectrum of target material I.

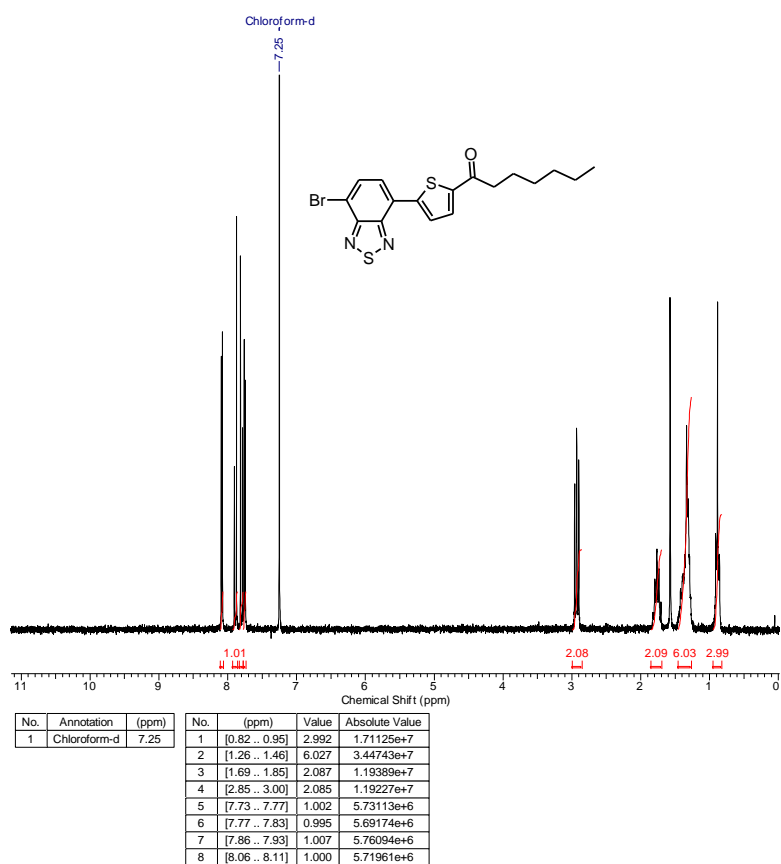


Figure S3. ^1H NMR spectrum of compound **3**.

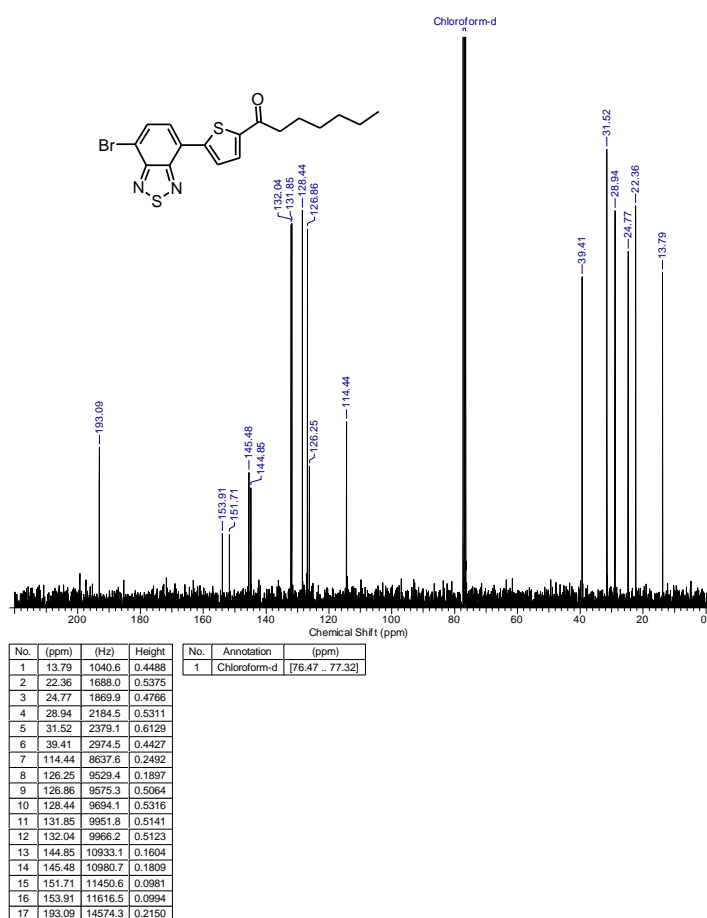


Figure S4. ^{13}C NMR spectrum of compound **3**.

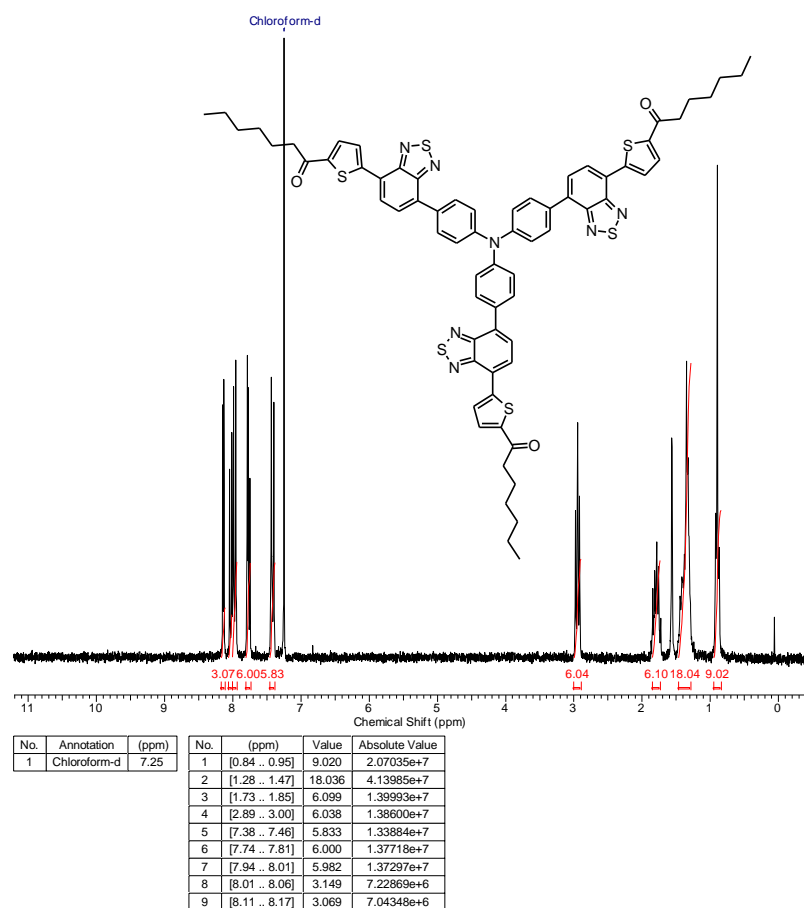


Figure S5. ^1H NMR spectrum of compound **5**.

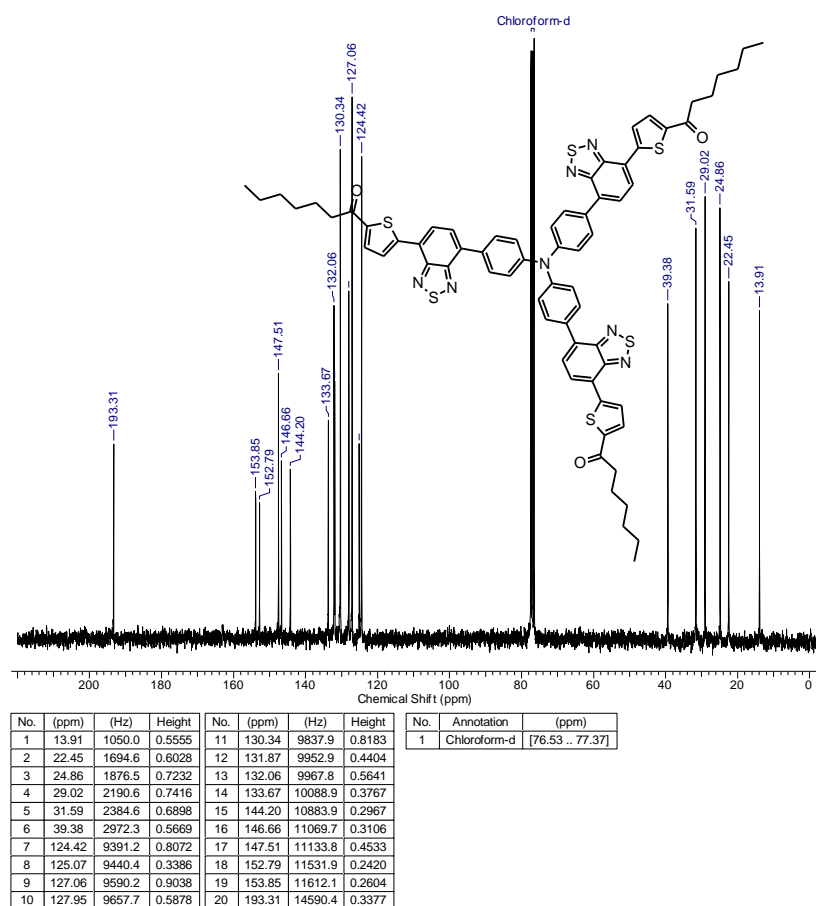


Figure S6. ^{13}C NMR spectrum of compound **5**.

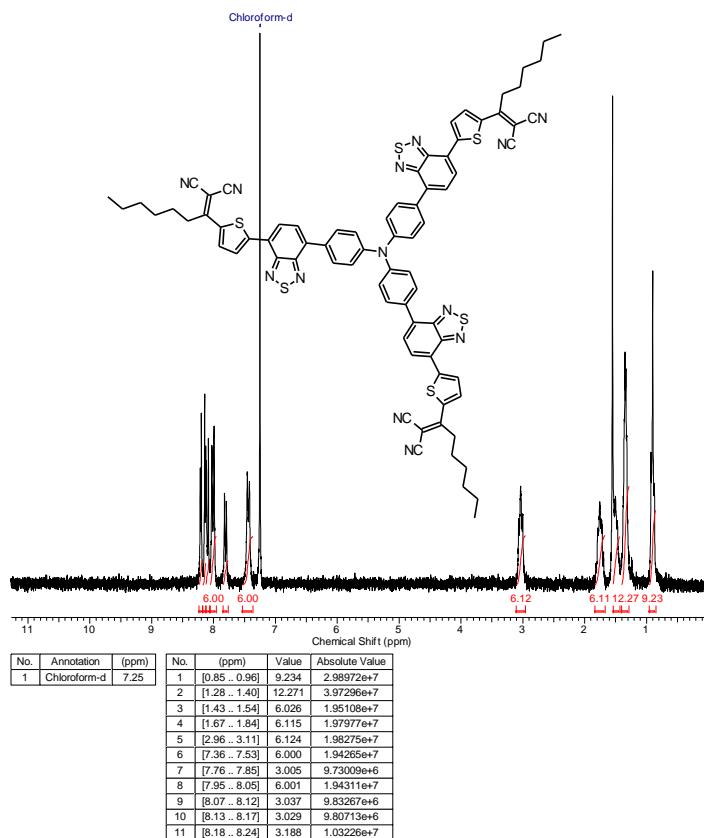


Figure S7. ^1H NMR spectrum of target material **III**.

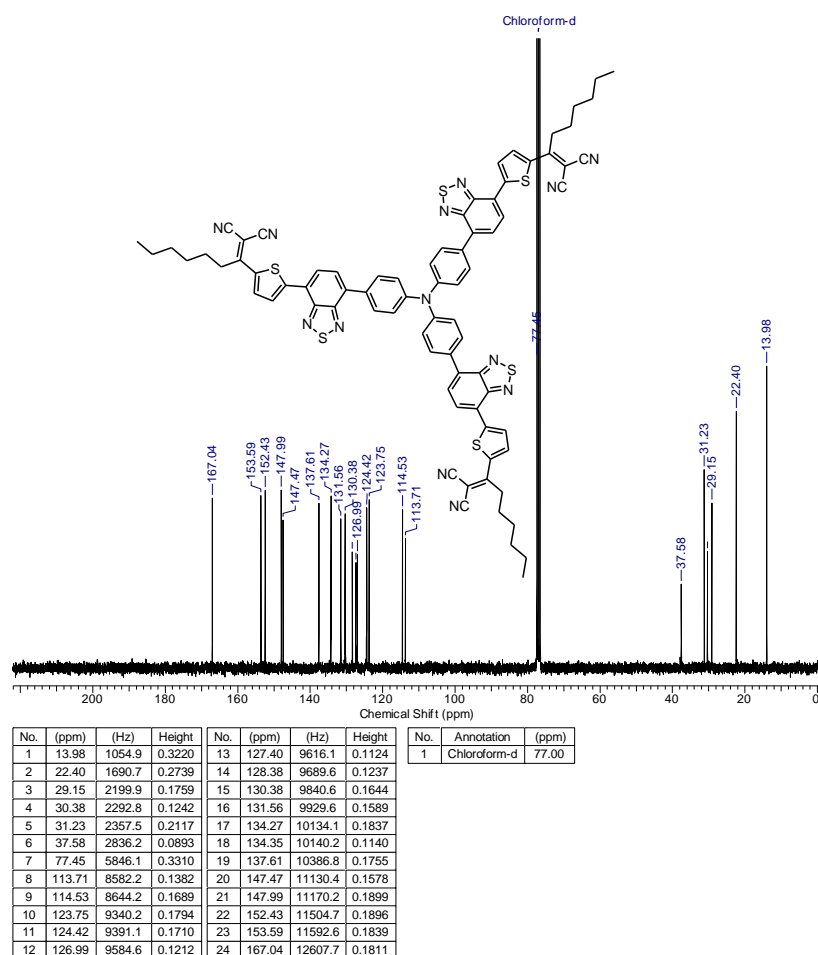


Figure S8. ^{13}C NMR spectrum of target material **III**.

Optical properties

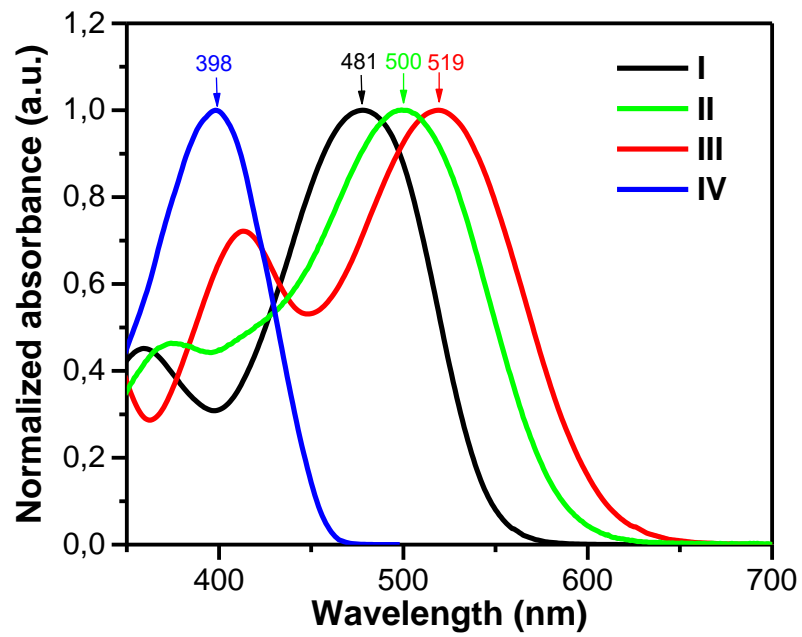


Figure S11. UV-vis normalized absorption spectra of materials studied in THF solution.

Mobility measurements

Hole mobility in films

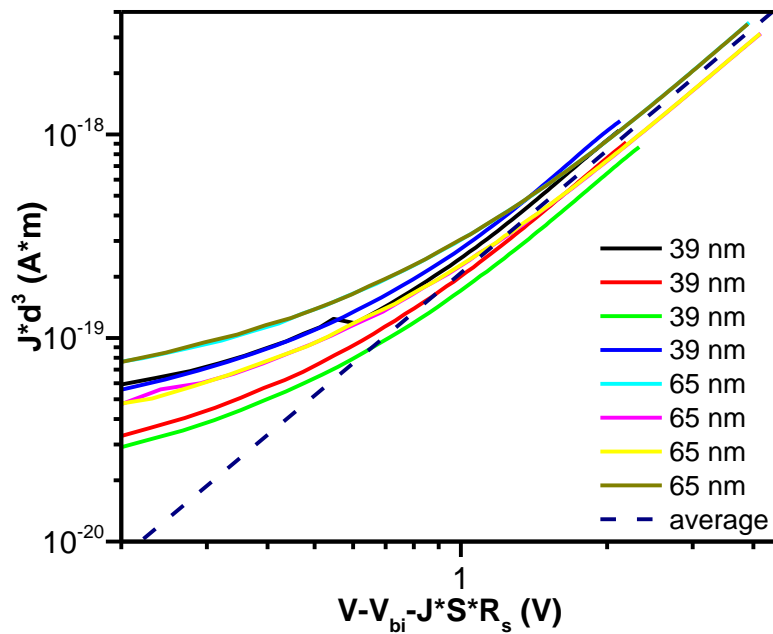


Figure S12. J - V characteristics of hole-only devices (solid lines). Jd^3 is plotted for two different layer thicknesses (39 ± 3 and 65 ± 3 nm) against the voltage, corrected for the built-in voltage and the electrode series resistance. Dashed line represents SCLC-fit, from which the hole mobility is extracted.

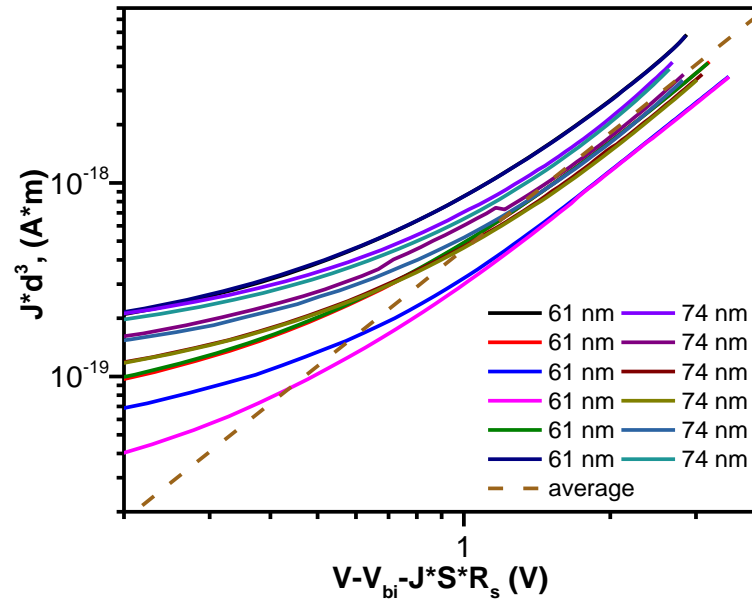


Figure S13. J - V characteristics of **II** hole only devices (solid lines). Jd^3 is plotted for two different layer thicknesses (61 ± 3 and 74 ± 3 nm) against the voltage, corrected for the built-in voltage and the electrode series resistance. Dashed line represents SCLC-fit, from which the hole mobility is extracted.

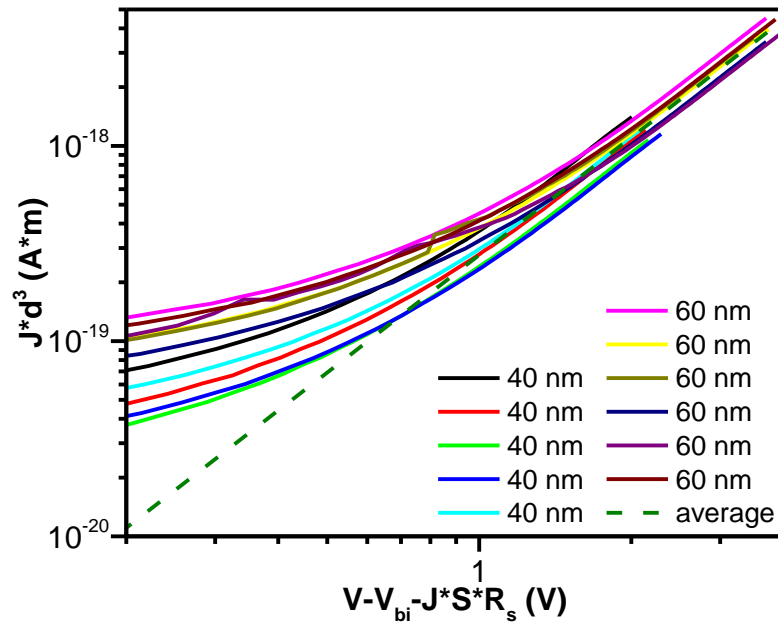


Figure S14. J - V characteristics of **III** hole only devices (solid lines). Jd^3 is plotted for two different layer thicknesses (40 ± 3 and 60 ± 3 nm) against the voltage, corrected for the built-in voltage and the electrode series resistance. Dashed line represents SCLC-fit, from which the hole mobility is extracted.

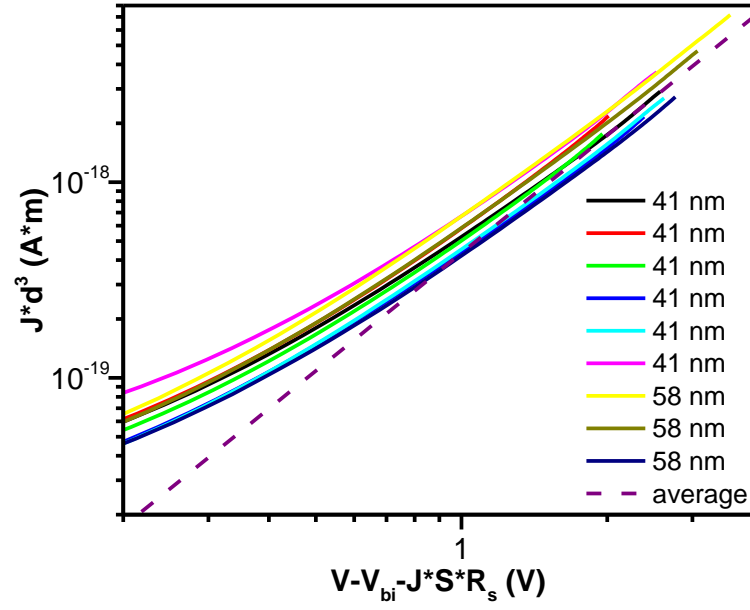


Figure S15. J – V characteristics of **IV**+PC₇₁BM(10%) hole only devices (solid lines). Jd^3 is plotted for two different layer thicknesses (41 ± 3 and 58 ± 3 nm) against the voltage, corrected for the built-in voltage and the electrode series resistance. Dashed line represents SCLC-fit, from which the hole mobility is extracted.

Electron mobility in films

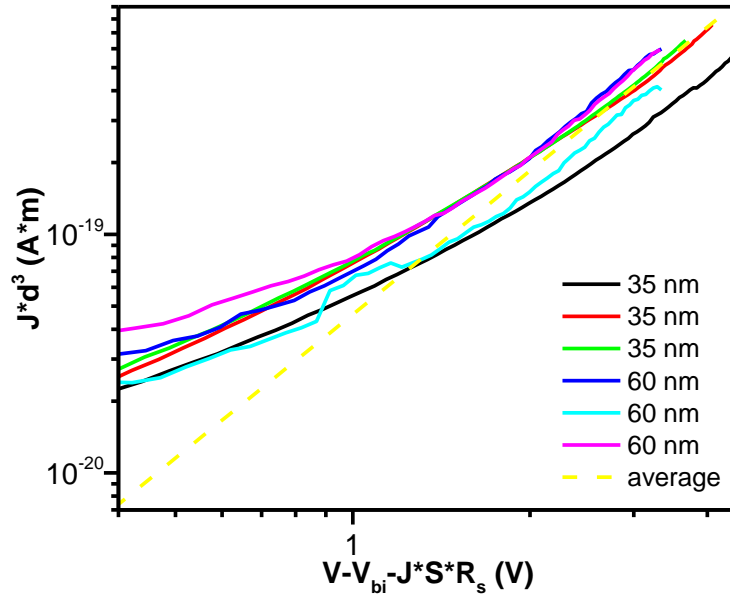


Figure S16. J – V characteristics of **I** electron only devices (solid lines). Jd^3 is plotted for two different layer thicknesses (35 ± 3 and 60 ± 3 nm) against the voltage, corrected for the built-in voltage and the electrode series resistance. Dashed line represents SCLC-fit, from which the electron mobility is extracted.

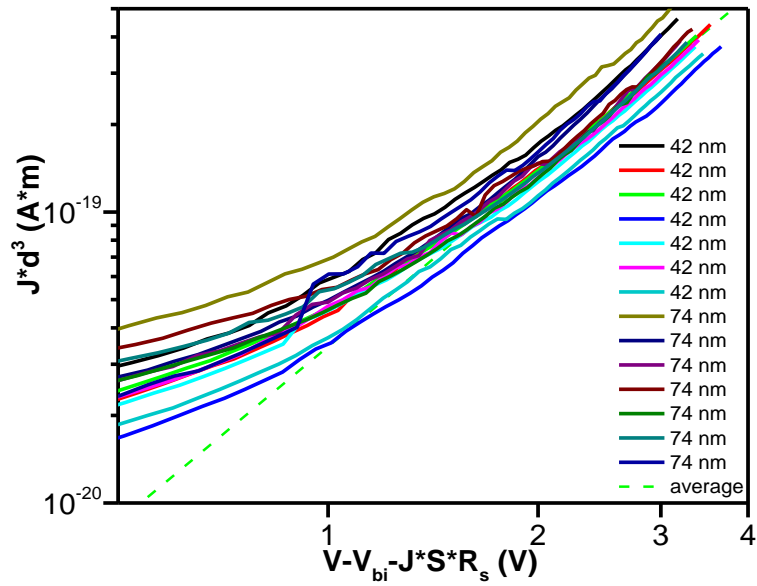


Figure S17. J – V characteristics of **II** electron only devices (solid lines). Jd^3 is plotted for two different layer thicknesses (42 ± 3 and 74 ± 3 nm) against the voltage, corrected for the built-in voltage and the electrode series resistance. Dashed line represents SCLC-fit, from which the electron mobility is extracted.

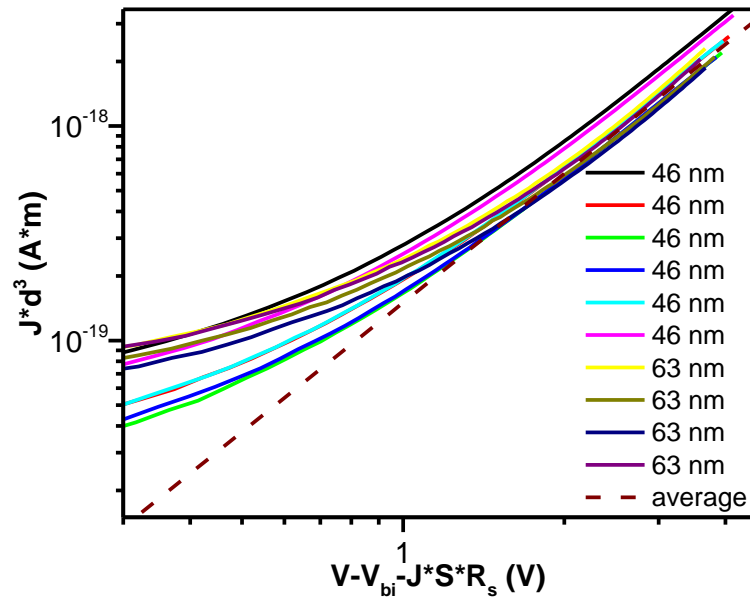


Figure S18. J – V characteristics of **III** electron only devices (solid lines). Jd^3 is plotted for two different layer thicknesses (46 ± 3 and 63 ± 3 nm) against the voltage, corrected for the built-in voltage and the electrode series resistance. Dashed line represents SCLC-fit, from which the electron mobility is extracted.

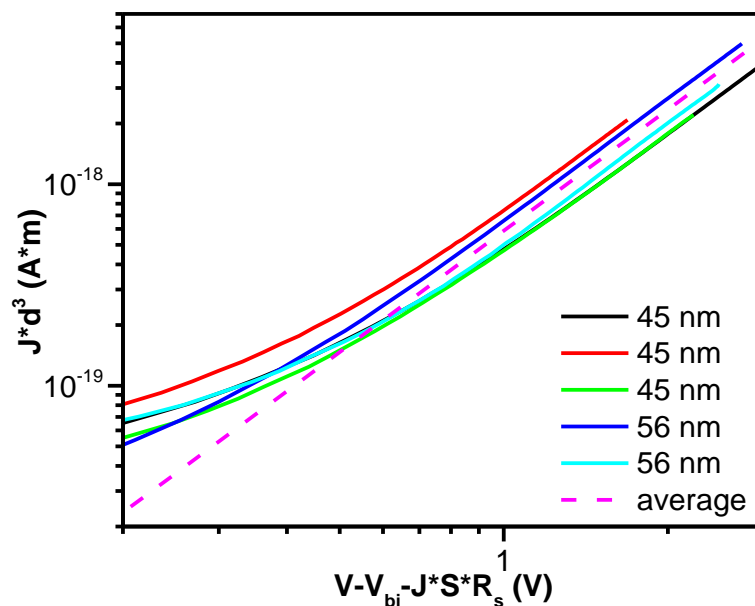


Figure S19. J - V characteristics of IV+PC₇₁BM(10%) electron only devices (solid lines). Jd^3 is plotted for two different layer thicknesses (45±3 and 56±3 nm) against the voltage, corrected for the built-in voltage and the electrode series resistance. Dashed line represents SCLC-fit, from which the electron mobility is extracted.

Photodetectors J - V curves, photovoltaic parameters, and EQE spectra.

The main photovoltaic properties of single-component photodetectors are presented in Figure S20 and summarized in Table S1. EQE and normalized EQE spectra are presented in Figure S21. Maximum EQE values and positions of peaks are summarized in Table S2.

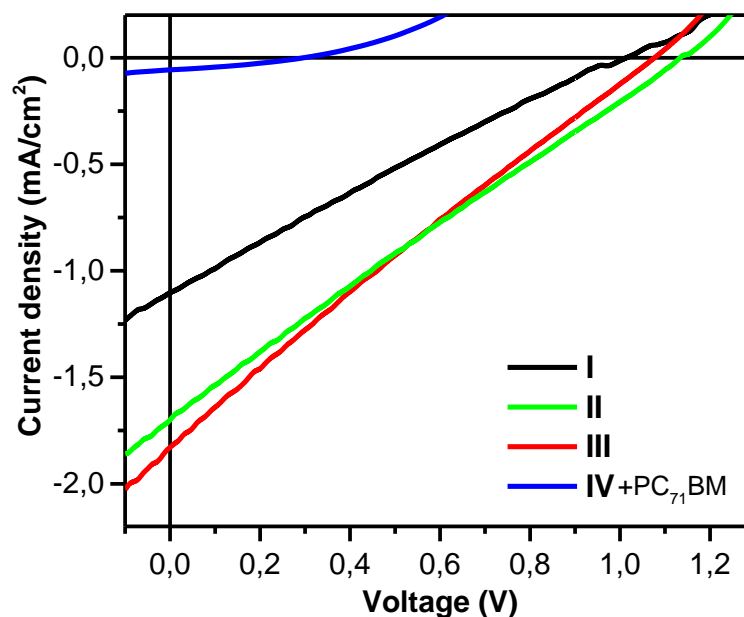


Figure S20. J - V curves of photodetectors under AM1.5G illumination (100 mW/cm²) of solar simulator (Newport 67005).

Table S1. The best photovoltaic parameters of single-component photodetectors under AM1.5G illumination (100 mW/cm^2).

Active layer material	J_{SC} , mA/cm^2	$J_{\text{SC EQE}}^*$, mA/cm^2	V_{OC} , V	FF, %	PCE, %
I	1.10	0.86	1.01	23.4	0.26
II	1.70	1.55	1.13	24.3	0.47
III	1.83	1.67	1.08	23.6	0.47
IV+PC₇₁BM(10%)	0.057	0.043	0.30	32.8	0.0055

Note: $*J_{\text{SC EQE}}$ is the short-circuit current integrated from the EQE spectrum.

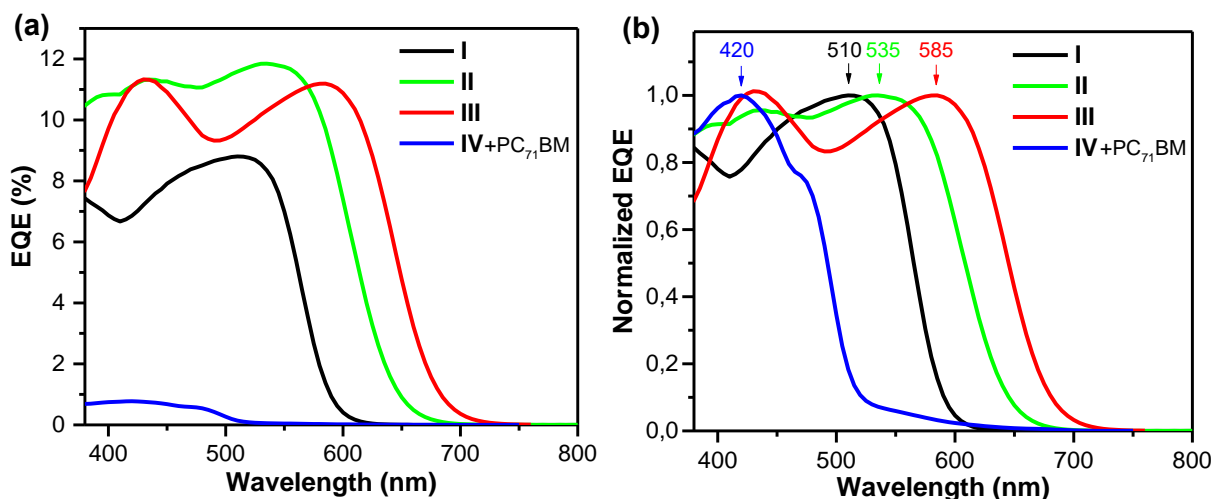


Figure S21. EQE (a) and normalized EQE (b) spectra of photodetectors. Arrows with numbers indicate the maxima of the spectra and their position.

Table S2. Maximum EQE values and positions of peaks.

Photoactive material	EQE, %	$\lambda_{\text{max}}^{\text{EQE}}$, nm
I	8.8	510
II	12	535
III	11	585
IV+PC₇₁BM(10%)	0.77	420